

Octal Buffer/Line Drivers, 3-State

CD74AC/ACT540 - Inverting CD74AC/ACT541 - Non-Inverting

Type Features:

- Buffered inputs
- Typical propagation delay: 4.5 ns @ Vcc = 5 V, TA = 25° C, CL = 50 pF

The CD54/74AC540, -541, and CD54/74ACT540, -541 octal buffer/line drivers use the RCA ADVANCED CMOS technology. The CD54/74AC/ACT540 are inverting 3-state buffers having two active-LOW output enables. The CD54/74AC/ACT541 are non-inverting 3-state buffers having two active-LOW output enables.

The CD74AC540, -541, and CD74ACT540, -541 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Industrial (-40 to +85°C) and Extended Industrial/Military (-55 to +125°C).

The CD54AC540, -541, and CD54ACT540, -541, available in chip form (H suffix), are operable over the -55 to +125°C temperature

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- ± 24-mA output drive current
 - Fanout to 15 FAST® ICs
 - Drives 50-ohm transmission lines

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TRUTH TABLE

	CD54/74AC/ACT540								
INPUTS	INPUTS OUTPUTS								
OE1, OE2	Α	Υ							
L	L	Н							
L	н	L							
н	х	Z							

TRUTH TABLE

	CD54/74AC/ACT541						
INPUTS		OUTPUTS					
OE1, OE2	Α	Υ					
L	L	L					
Ł	н	Н					
н	х	Z					

H = High Voltage

L = Low Voltage

X = Immaterial

Z = High Impedance

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DC SUPPLY-VOLTAGE (V_{CC}) DC INPUT DIODE CURRENT, I_{IK} (for $V_{I} < -0.5$ or $V_{I} > V_{CC} + 0.5$ V) DC OUTPUT DIODE CURRENT, I_{OK} (for $V_{O} < -0.5$ or $V_{O} > V_{CC} + 0.5$ V) DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I_{O} (for $V_{O} > -0.5$ or $V_{O} < V_{CC} + 0.5$ V) DC V_{CC} OR GROUND CURRENT (I_{CC} or I_{GND}) PACKAGE THERMAL IMPEDANCE, θ_{JA} (see Note 1): E package	
M package	
STORAGE TEMPERATURE (T _{stg})	65 to +150°C
At distance $1/16\pm1/32$ in. $(1.59\pm0.79$ mm) from case for 10 s maximum	

 $^{^{\}star}$ For up to 4 outputs per device: add ± 25 mA for each additional output.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	27	LIN	LIMITO	
CHARACIERISTIC	1 % " M"	MIN.	MAX.	UNITS
Supply-Voltage Range, V _∞ *: (For T _A = Full Package-Temperature Range) AC Types ACT Types	ico.	1.5 4.5	5.5 5.5	V
DC Input or Output Voltage, V _I , V _O		0	Vcc	V
Operating Temperature, T _A :		-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)		0 0 0	50 20 10	ns/V ns/V ns/V

^{*}Unless otherwise specified, all voltages are referenced to ground.

TERMINAL ASSIGNMENT DIAGRAMS



Technical Data	

STATIC ELECTRICAL CHARACTERISTICS: AC Series

				AMBIENT TEMPERATURE (TA) - °C							
CHARACTERISTICS		TEST CO	NDITIONS	V _{cc}	+2	25	-40 to	+85	-55 to +125		UNITS
			l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2	_	1.2	-	1.2	_	
Voltage	ViH			3	2.1	_	2.1	_	2.1		V
				5.5	3.85	_	3.85	_	3.85		
Low-Level Input				1.5	_	0.3	_	0.3		0.3	
Voltage	VIL			3	_	0.9	_	0.9		0.9] v
				5.5		1.65	_	1.65		1.65	
High-Level Output			-0.05	1.5	1.4	_	1.4	_	1.4		
Voltage	V_{OH}	V _{IH}	-0.05	3	2.9		2.9	_	2.9	_	
		or	-0.05	4.5	4.4	_	. 4.4	_	4.4	_]
		VIL	-4	3	2.58	_	2.48		2.4] v
			-24	4.5	3.94	- 10 A	3.8	_	3.7	_]
		#, * {	-75	5.5	- :	St. 38	3.85	<u> </u>		_]
		7, 1	-50	5.5	v 25	-	1		3.85	_]
Low-Level Output		,	0.05	1.5	32-	0.1	_	0.1	_	0.1	
Voltage	Vol	VIH	0.05	3	-0	0.1	_	0.1		0.1	1
		or	0.05	4.5	•	0.1		0.1	_	0.1]
		VIL	12	3		0.36	_	0.44	_	0.5	V
			24	4.5	-	0.36	_	0.44		0.5	1
		#, * \	75	5.5	_		_	1.65		_]
		#, ^	50	5.5	_	_	_	_		1.65	1
Input Leakage Current	l ₁	V _{cc} or GND		5.5	-	±0.1	_	±1		±1	μΑ
3-State Leakage Current	loz	V _{IH}									
		V _{1L}									
		V _o =		5.5	_	±0.5	_	±5		±10	μΑ
		Vcc		0.0	İ						
		or						Ì			
		GND									
Quiescent Supply Current, MSI	lcc	V _{CC} or GND	0	5.5	_	8	_	80	_	160	μΑ

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

					AMBIENT TEMPERATURE (T _A) - °C							
CHARACTERISTICS		TEST CONDITIONS		V _{cc}	+:	+25		-40 to +85		-55 to +125		
		V, (V)	l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.]	
High-Level Input Voltage	V _{IH}			4.5 to 5.5	2	_	2	_	2	_	v	
Low-Level Input Voltage	VIL			4.5 to 5.5		0.8	_	0.8		0.8	v	
High-Level Output		ViH	-0.05	4.5	4.4		4.4		4.4			
Voltage	VoH	or V _{IL}	-24	4.5	3.94		3.8		3.7		v	
		#, * \	-75	5.5	_		3.85					
		1	-50	5.5					3.85			
Low-Level Output		VIH	0.05	4.5		0.1	_	0.1		0.1]	
Voltage Vol	or V _{IL}	24	4.5		0.36	-3:	0.44		0.5	v		
		#, * }	75	5.5		-35.	4.0	1.65				
			50	5.5	_	1-13	-	27.		1.65		
Input Leakage Current	l ₁	V _{CC} or GND		5 .5	1-36	±0.1	W.	±1		, ±1	μΑ	
3-State Leakage Current	loz	V _{IH} or V _{IL}										
		$V_0 = V_{CC}$ or GND		5.5	_	±0.5		±5	-	±10	μΑ	
Quiescent Supply Current, MSI	lcc	V _{cc} or GND	0	5.5	_	8	_	80		160	μΑ	
Additional Quiescent S Current per Input Pi TTL Inputs High 1 Unit Load		V _{cc} -2.1		4.5 to 5.5		2.4		2.8		3	mA	

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

ACT INPUT LOADING TABLE

INPUT	UNIT LOAD*				
	540	541			
DATA	1.42	0.5			
OE1, OE2	1.3	1.3			

*Unit load is Δl_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

^{*} Test verifies a minimum 50-ohm transmission-line-drive capability at +85° C, 75 ohms at +125° C.

SWITCHING CHARACTERISTICS: AC Series; t,, t, = 3 ns, C, = 50 pF

			AMBI	T			
CHARACTERISTICS	SYMBOL	(v)	-40 to +85		-55 to +125		UNITS
		(•,	MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Data to Output AC540	tpLH tpHL	1.5 3.3* 5†	2.4 1.8	77 8.6 6.2	2.4 1.7	85 9.5 6.8	ns
AC541	t _{PLH} t _{PHL}	1.5 3.3 5	2.8 2.1	89 9.9 7.1	2.7 2	98 10.9 7.8	ns
Enable, to Output to Output	t _{PZL} t _{PZH}	1.5 3.3 5	4.6 3.1	136 16.4 10.9	 4.5 3	150 18 12	ns
Disable to Output to Output	t _{PLZ} t _{PHZ}	1.5 3.3 5	3.9 3.1	136 13.6 10.9	— 3.8 3	150 15 12	ns
Power Dissipation Capacitance AC540 AC541	C _{PO} ‡			Typ.		Гур. Гур.	pF
Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	表势	4 Typ. (@ 25°C		٧
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	Vole See Fig. 1	5	OW	1 Typ. (@ 25°C		٧
Input Capacitance	Cı		9 -	10	_	10	рF
3-State Output Capacitance	Co	-	_	15	_	15	pF

SWITCHING CHARACTERISTICS: ACT Series; t, t, = 3 ns, C, = 50 pF

		V _{cc} (V)	AMBI	T			
CHARACTERISTICS	SYMBOL		-40 1	-40 to +85		=125	UNITS
			MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Data to Output ACT540	t _{PLH} t _{PHL}	5†	1.9	6.5	1.8	7.2	ns
ACT541	t _{PLH} t _{PHL}	5†	2.1	7.5	2.1	8.2	ns
Enable to Output	t _{PZL} t _{PZH}	5	3.5	12.2	3.4	13.4	ns
Disable to Output	t _{PLZ} t _{PHZ}	5	3.5	12.2	3.4	13.4	ns
Power Dissipation Capacitance ACT540 ACT541	Сро§	_	1	Тур. Тур.	60 Typ. 60 Typ.		pF
Min. (Valley) VoH During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C			V	
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5	1 Typ. @ 25°C			v	
Input Capacitance	Cı	_	_	10	_	10	pF
3-State Output Capacitance	Co	_		15	_	15	pF

*3.3 V: min. is @ 3.6 V

 C_{PD} is used to determine the dynamic power consumption, per channel. For AC series, $P_D = V_{CC}^2 \, f_i \, (C_{PD} + C_L)$ For ACT series, $P_D = V_{CC}^2 \, f_i \, (C_{PD} + C_L) + V_{CC} \, \Delta I_{CC}$ where $f_i = input \, free$

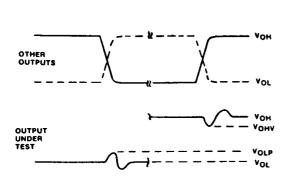
 $f_i = input frequency$ C_L = output load capacitance

 V_{cc} = supply voltage.

max. is @ 3 V

†5 V: min. is @ 5.5 V max. is @ 4.5 V

PARAMETER MEASUREMENT INFORMATION



NOTES:

- 1. V_{OHV} and V_{OLP} are measured with respect to a ground reference near the output under test.
- REFERENCE NEAR THE OUTPUT UNDER LEST.

 2. INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS:

 PRR ≤ 1 MHz, t_T = 3 ns, t₁ = 3 ns, SKEW 1 ns.

 3. R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED.

 IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 µF CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

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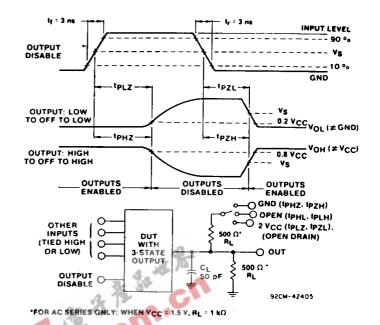


Fig. 1 - Simultaneous switching transient waveforms,

Fig. 2 - Three-state propagation delay waveforms and test circuit.

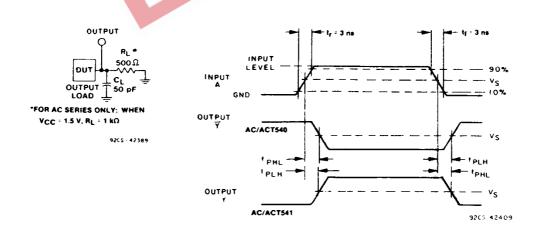


Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	CD54/74ACT
Input Level	V _{cc}	3 V
Input Switching Voltage, Vs	0.5 V _{cc}	1.5 V
Output Switching Voltage, Vs	0.5 V _{cc}	0.5 V _{cc}





26-May-2007

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
CD54AC541F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54ACT540F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54ACT541F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74AC540M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC540ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC540MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC541EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC541M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541SM	OBSOLETE	SSOP	DB	20		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541SM96	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541SM96E4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC541SM96G4	ACTIVE	SSOP	DB	20	2000	TBD	Call TI	Call TI
CD74ACT540E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT540EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT540M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT540M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT540M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT540M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT540ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT540MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541E	ACTIVE	PDIP	N	20	20	Pb-Free	CU NIPDAU	N / A for Pkg Type



PACKAGE OPTION ADDENDUM

26-May-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						(RoHS)		
CD74ACT541EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT541M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541SM	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI
CD74ACT541SM96	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541SM96E4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT541SM96G4	ACTIVE	SSOP	DB	20	2000	TBD	Call TI	Call TI

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

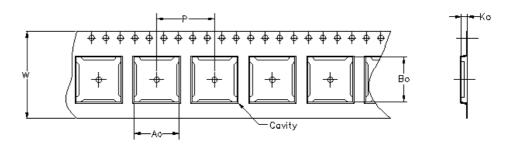
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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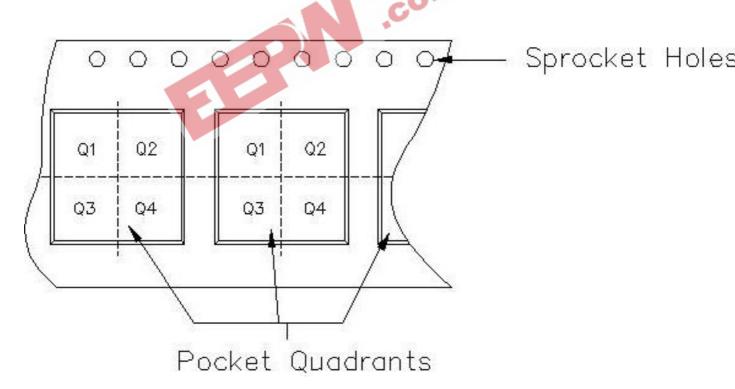
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Carrier tape design is defined largely by the component lentgh, width, and thickness

Ao = Dimension designed to accommodate the component width.							
Bo = Dimension designed to accommodate the component length.							
Ko = Dimension designed to accommodate the component thickness.							
W = Overall width of the carrier tape. 🐪 🔥							
P = Pitch between successive cavity benters.							



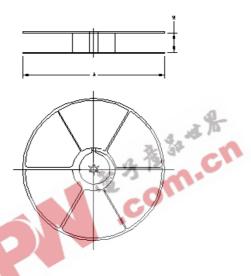
TAPE AND REEL INFORMATION



PACKAGE MATERIALS INFORMATION

19-May-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC541M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1
CD74AC541SM96	DB	20	MLA	330	16	8.2	7.5	2.5	12	16	Q1
CD74ACT540M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1
CD74ACT541M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1
CD74ACT541SM96	DB	20	MLA	330	16	8.2	7.5	2.5	12	16	Q1



TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CD74AC541M96	DW	20	MLA	333.2	333.2	31.75
CD74AC541SM96	DB	20	MLA	342.9	336.6	28.58
CD74ACT540M96	DW	20	MLA	333.2	333.2	31.75
CD74ACT541M96	DW	20	MLA	333.2	333.2	31.75
CD74ACT541SM96	DB	20	MLA	342.9	336.6	28.58

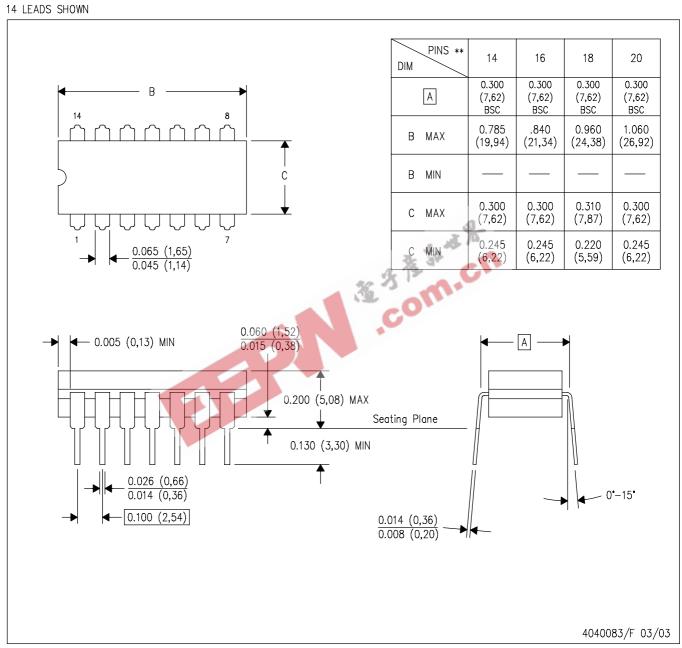


TEXAS INSTRUMENTS www.ti.com









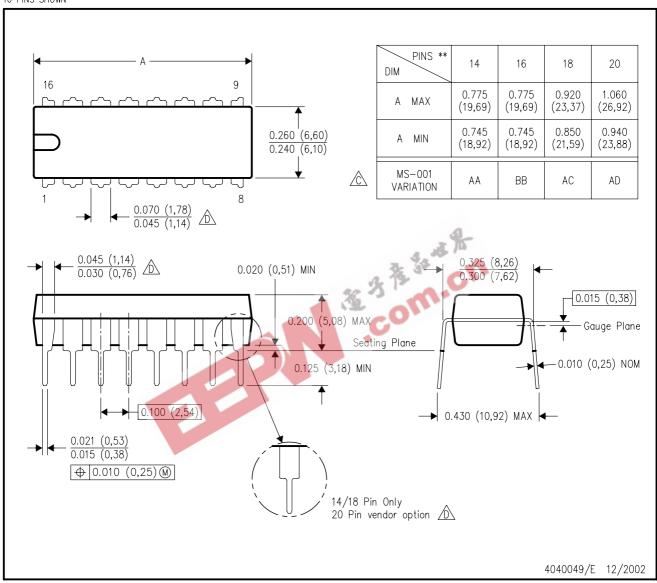
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



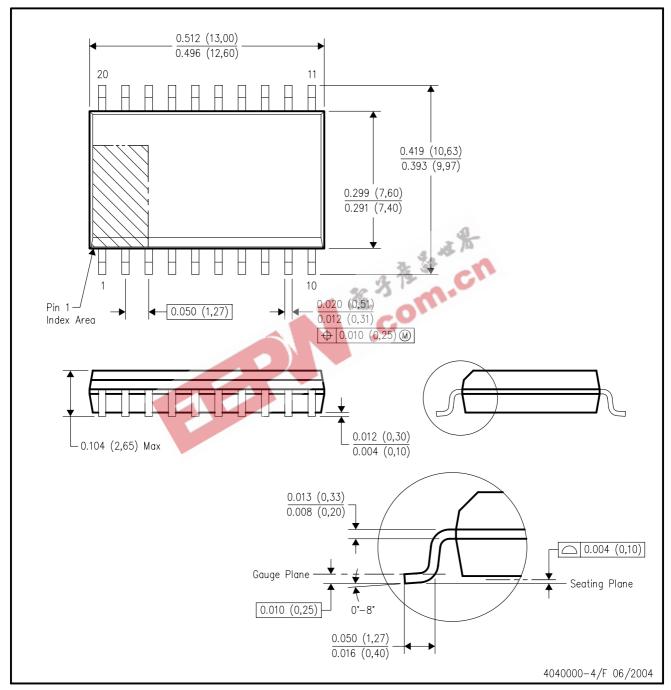
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

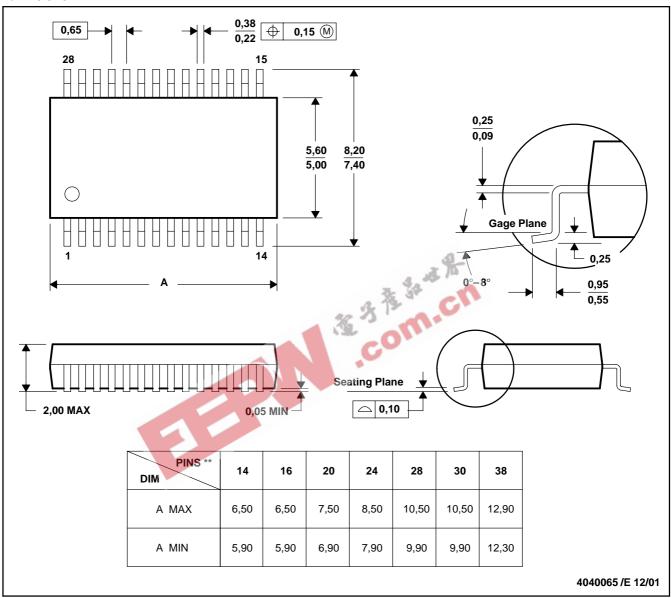
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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